Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

Between 0.130 inches and 0.146 inches

Overall Diameter:

Between 0.063 inches and 0.067 inches

End Application:

Nuclear power plants

Mounting Facility Quantity:

2

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

15.00 regulator voltage, dc and 11.40 reverse voltage, instantaneous

Current Rating Per Characteristic:

0.50 microamperes collector current, dc peak

Terminal Type And Quantity:

2 bonding pad

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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